Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** 6.540 inches **Overall Height:** 1.360 inches **Overall Width:** 5.910 inches **End Application:** 6130-01-573-8037 **Mounting Facility Quantity:** 8 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon carbide Voltage Rating In Volts Per Characteristic: 1200.0 collector-to-emitter voltage, instantaneous **Current Rating Per Characteristic:** 1400.0 amperes emitter current, dc **Product Name:** Module, igbt **Terminal Type And Quantity:** 9 threaded hole Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0